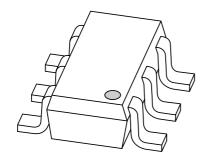
DISCRETE SEMICONDUCTORS

DATA SHEET



1PS74SB43Schottky barrier diode

Product specification

1999 Dec 10





Schottky barrier diode

1PS74SB43

FEATURES

- · Ultra fast switching speed
- · Low forward voltage
- · Fast recovery time
- · Guard ring protected
- Small plastic SMD package
- Capability of absorbing very high surge current.

APPLICATIONS

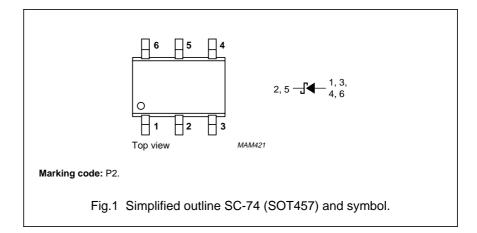
- Rectification
- · Circuit protection
- · Polarity protection
- Switched-mode power supplies.

DESCRIPTION

Planar Schottky barrier diode encapsulated in an SC-74 (SOT457) small plastic SMD package.

PINNING

PIN	DESCRIPTION
1	anode
2	cathode
3	anode
4	anode
5	cathode
6	anode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	40	V
I _F	continuous forward current		_	1	Α
I _{FSM}	non-repetitive peak forward current	tp = 8.3 ms; half sinewave; JEDEC method; note 1	_	27	А
I _{RSM}	non-repetitive peak reverse current	tp = 100 μs	_	0.5	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C

Note

1. Pins 1, 3, 4 and 6 are connected in parallel; pins 2 and 5 are connected in parallel.

Philips Semiconductors Product specification

Schottky barrier diode

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	continuous forward voltage	see Fig.2; note 1			
		I _F = 0.1 A	280	330	mV
		I _F = 1 A	460	500	mV
I _R	continuous reverse current	V _R = 10 V; note 1; see Fig.3	15	40	μΑ
		$V_R = 40 \text{ V}$; note 1; see Fig.3	60	300	μΑ
C _d	diode capacitance	$V_R = 4 \text{ V}$; f = 1 MHz; see Fig.4	65	80	pF

Note

1. Pulsed test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	200	K/W

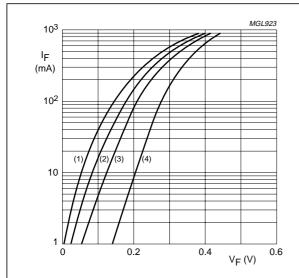
Note

1. Refer to SC-74 (SOT457) standard mounting conditions.

Schottky barrier diode

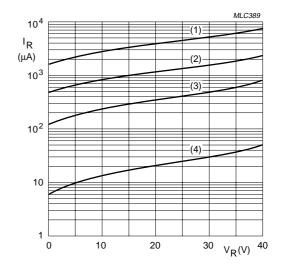
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GRAPHICAL DATA



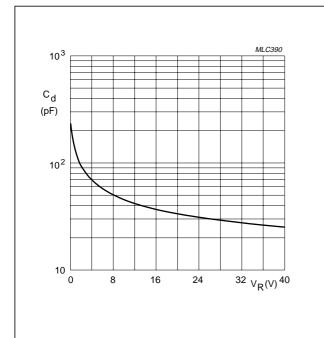
- (1) $T_{amb} = 125 \,^{\circ}C$.
- (2) $T_{amb} = 100 \, ^{\circ}C$.
- (3) $T_{amb} = 75 \, ^{\circ}C.$
- (4) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 100 \, ^{\circ}C$.
- (3) $T_{amb} = 75 \, ^{\circ}C$.
- (4) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}.$

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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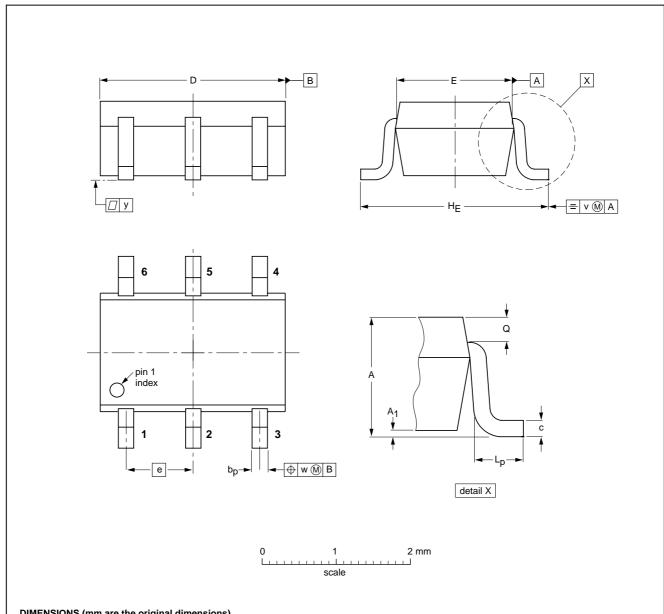
Schottky barrier diode

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT457



DIMENSIONS (mm ar	re the original dimensions)

UN	IT	A	A ₁	bp	С	D	E	е	HE	Lp	Q	v	w	у
mr	n	1.1 0.9	0.1 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE		REFER	EUROPEAN ISSUE DATE			
VERSION			EIAJ	PROJECTIO		ISSUE DATE
SOT457			SC-74			97-02-28

Philips Semiconductors Product specification

Schottky barrier diode

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DEFINITIONS

Data Sheet Status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				

LIFE SUPPORT APPLICATIONS

Application information

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Where application information is given, it is advisory and does not form part of the specification.

Schottky barrier diode

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